

CSD20060D-Silicon Carbide Schottky Diode

ZERO RECOVERY® RECTIFIER

\mathbf{V}_{RRM} = 600 V $\mathbf{I}_{F(AVG)}$ = 20 A \mathbf{Q}_{c} = 56 nC

Features

- 600-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway

Applications

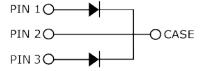
- Switch Mode Power Supplies
- Power Factor Correction
- Typical PFC P_{out}: 2000W-4000W Motor Drives
 - Typical Power : 5HP-10HP

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V _{RRM}	Repetitive Peak Reverse Voltage	600	V		
V _{RSM}	Surge Peak Reverse Voltage	600	V		
V _{DC}	DC Blocking Voltage	600	V		
$\mathrm{I}_{\mathrm{F(AVG)}}$	Average Forward Current (Per Leg/Device)	10/20 16.5/33	А	T _c =150°C T _c =125°C	
$I_{_{F(Peak)}}$	Peak Forward Current	25/50	A	$T_{c}=125^{\circ}, T_{REP}<1 \text{ mS, Duty}=0.5$	
\mathbf{I}_{FRM}	Repetitive Peak Forward Surge Current (Per Leg/Device)	43/86 29/58	A	$T_c=25$ °C, $t_p=10$ ms, Half Sine Wave $T_c=125$ °C, $t_p=10$ ms, Half Sine Wave	
\mathbf{I}_{FSM}	Non-Repetitive Peak Forward Surge Current (Per Leg)	77	A	$T_c = 25^{\circ}C$, $t_p = 1.5$ ms, Half Sine Wave	
I _{fsm}	Non-Repetitive Peak Forward Surge Current (Per Leg/Device)	250/500	A	$T_c=25$ °C, $t_p=10$ µs, Pulse	
P_{tot}	Power Dissipation (Per Leg)	138 46	w	T _c =25°C T _c =125°C	
T_{j} , T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°c		
	TO-247 Mounting Torque	1 8.8	Nm Ibf-in	M3 Screw 6-32 Screw	

Package





Part Number	Package	Marking
CSD20060D	TO-247-3	CSD20060

Datasheet: CSD20060D Rev. Q



Electrical Characteristics (Per Leg)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V _F	Forward Voltage	1.5 2.0	1.8 2.4	V	$I_F = 10 \text{ A} \text{ T}_J = 25^{\circ}\text{C}$ $I_F = 10 \text{ A} \text{ T}_J = 175^{\circ}\text{C}$	
I _R	Reverse Current	50 100	200 1000	μA	$V_{R} = 600 V T_{J} = 25^{\circ}C$ $V_{R} = 600 V T_{J} = 175^{\circ}C$	
Q _c	Total Capacitive Charge	28		nC	$V_{R} = 600 \text{ V}, I_{F} = 10 \text{ A}$ $di/dt = 500 \text{ A}/\mu\text{s}$ $T_{J} = 25^{\circ}\text{C}$	
С	Total Capacitance	550 65 50		pF	$V_{R} = 0 V, T_{J} = 25^{\circ}C, f = 1 MHz$ $V_{R} = 200 V, T_{J} = 25^{\circ}C, f = 1 MHz$ $V_{R} = 400 V, T_{J} = 25^{\circ}C, f = 1 MHz$	

Note:

1. This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Тур.	Unit
$R_{_{ ext{ hetaJC}}}$	Thermal Resistance from Junction to Case	1.08** 0.54*	°C/W

** Per Leg, * Both Legs

Typical Performance (Per Leg)

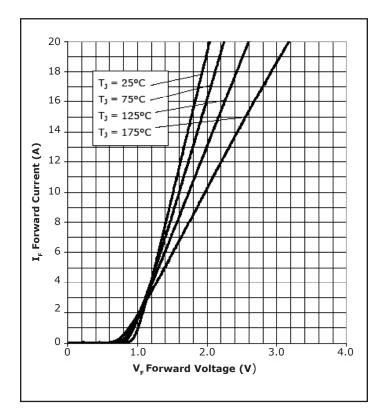


Figure 1. Forward Characteristics

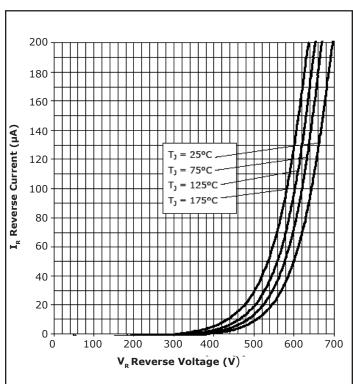


Figure 2. Reverse Characteristics



Typical Performance (Per Leg)

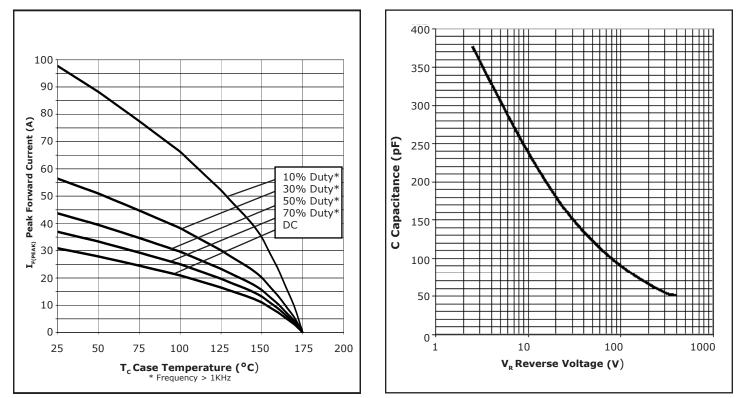


Figure 3. Current Derating

Figure 4. Capacitance vs. Reverse Voltage

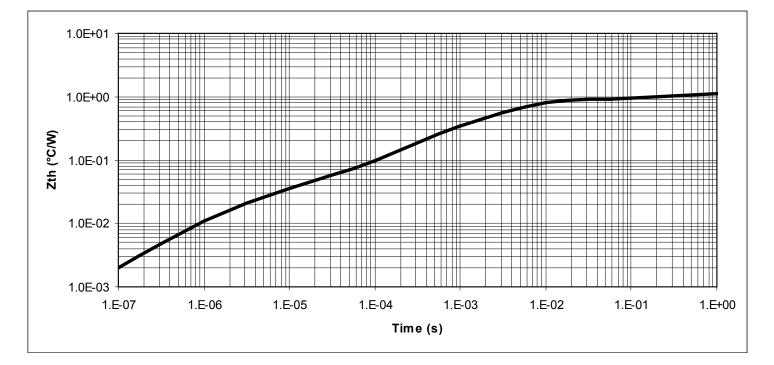


Figure 5. Transient Thermal Impedance

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Typical Performance (Per Leg)

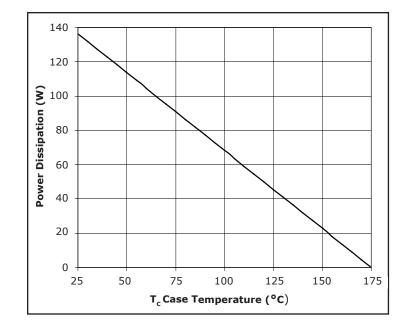
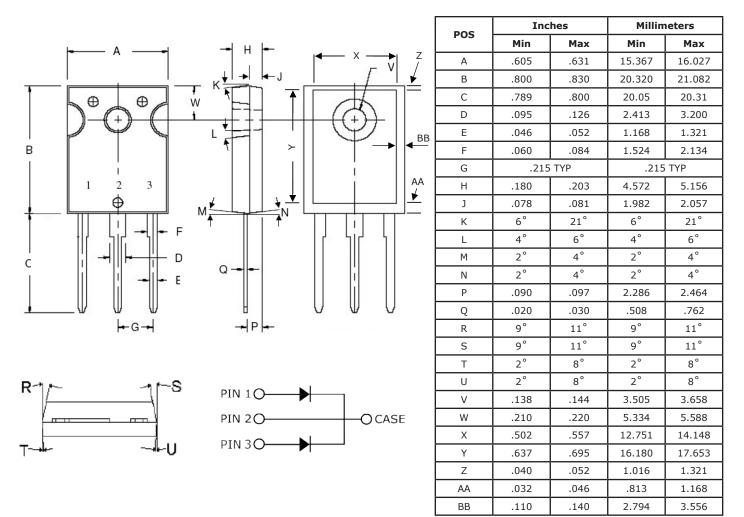


Figure 6. Power Derating



Package Dimensions

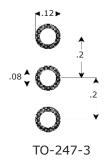
Package TO-247-3



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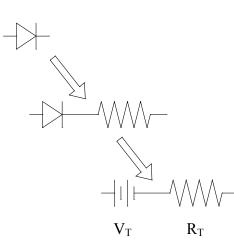


Recommended Solder Pad Layout



Part Number	Package	Marking	
CSD20060D	TO-247-3	CSD20060	

Diode Model



eg

 $Vf_T = V_T + If^*R_T$

$$\begin{split} V_{T^{=}} 0.92 + (T_{j} * -1.35*10^{-3}) \\ R_{T^{=}} 0.052 + (T_{j} * 0.29*10^{-3}) \end{split}$$

Note: T_i = Diode Junction Temperature In Degrees Celcius

"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006. This part number was released previously with Sn/Pb solder plating as a standard industry finish. For more information please contact power_sales@cree.com "

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, air traffic control systems, or weapons systems.

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